

### Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	$I_D$
40V	3mΩ@10V	90A
	4mΩ@4.5V	

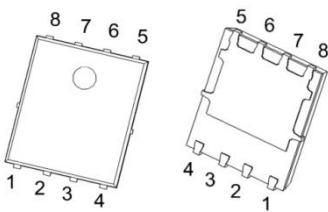
### Feature

- Fast switching speed
- Surface mount package
- Reliable and Rugged
- ROHS Compliant & Halogen-Free

### Applications

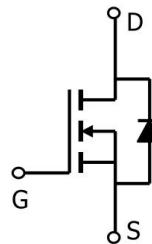
- DC-DC Converters.
- Motor Control.
- Portable equipment application

### Package

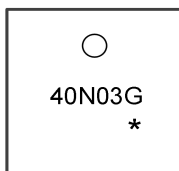


PDFN5X6-8L

### Circuit diagram



### Marking



40N03G      =Device Code  
\*              =Month Code

**Absolute maximum ratings (Ta=25°C unless otherwise noted)**

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V <sub>DS</sub>	40	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Continuous Drain Current <sup>1</sup> (T <sub>c</sub> =25°C)	I <sub>D</sub>	90	A
Pulsed Drain Current <sup>2</sup>	I <sub>DM</sub>	360	A
Single Pulse Avalanche Energy <sup>3</sup>	E <sub>AS</sub>	376	mJ
Total Power Dissipation <sup>4</sup> (T <sub>c</sub> =25°C)	P <sub>D</sub>	61.4	W
Thermal Resistance Junction-Case <sup>1</sup>	R <sub>θJC</sub>	2.04	°C/W
Thermal Resistance Junction-Ambient	R <sub>θJA</sub>	65	°C/W
Storage Temperature Range	T <sub>STG</sub>	-55 to 150	°C
Operating Junction Temperature Range	T <sub>J</sub>	-55 to 150	°C

**Electrical characteristics (Ta=25°C, unless otherwise noted)**

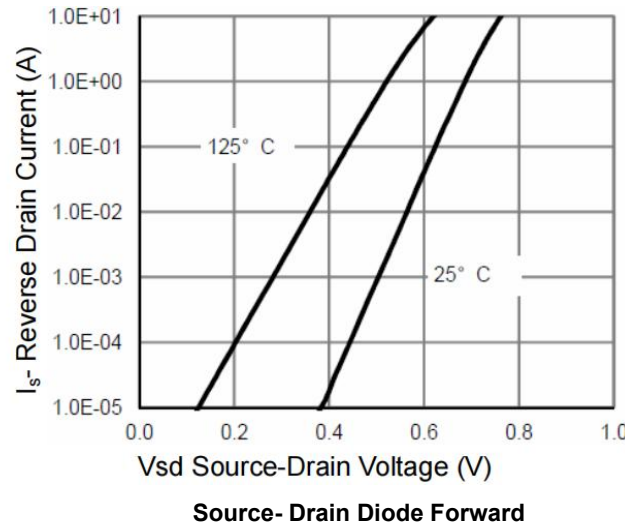
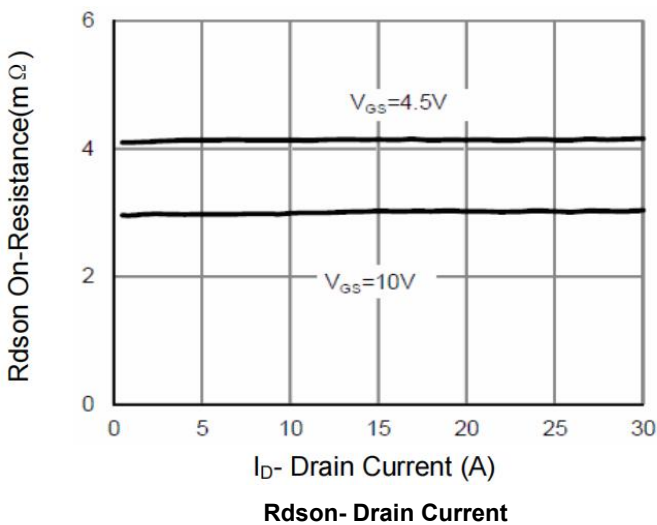
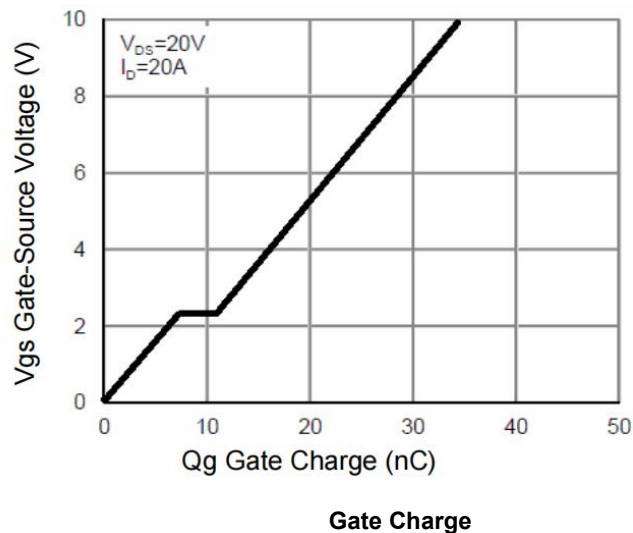
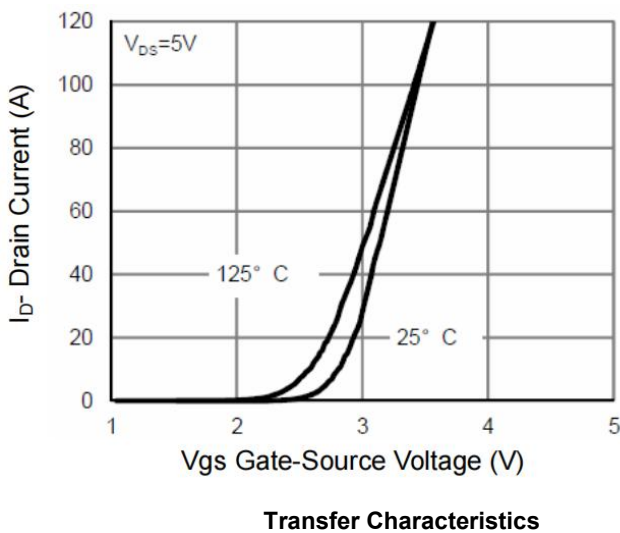
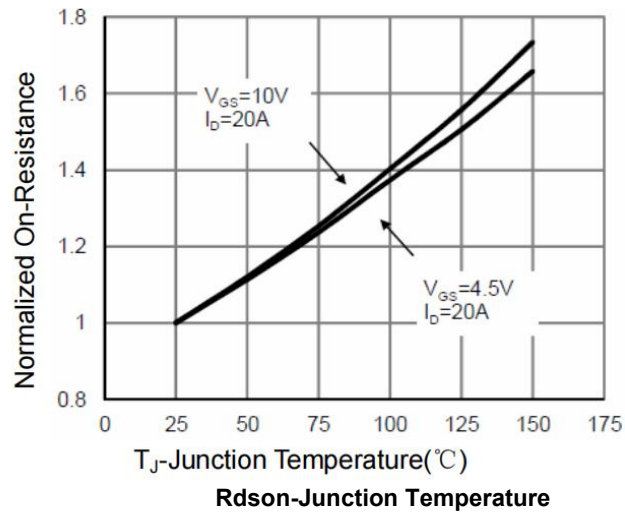
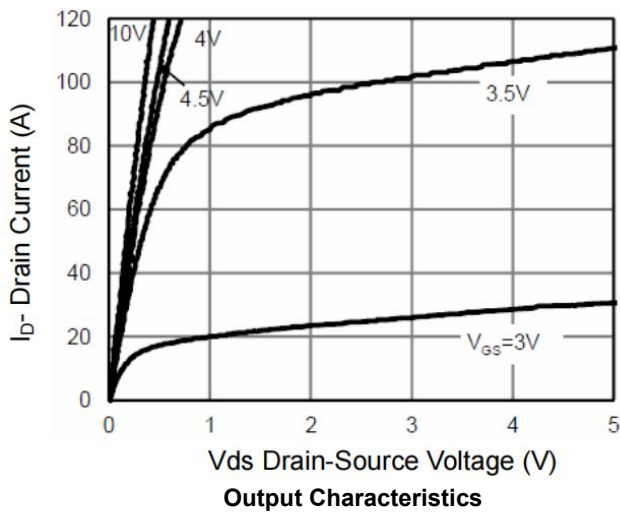
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V , I <sub>D</sub> =250uA	40	---	---	V
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =32V , V <sub>GS</sub> =0V , T <sub>J</sub> =25°C	---	---	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V , V <sub>DS</sub> =0V	---	---	±100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =250uA	1	1.5	2.5	V
Static Drain-Source On-Resistance <sup>2</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V , I <sub>D</sub> =30A	---	3	3.7	mΩ
		V <sub>GS</sub> =4.5V , I <sub>D</sub> =30A	---	4	5.3	
<b>Dynamic characteristics</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =20V , V <sub>GS</sub> =0V , f=1MHz	---	2800	---	pF
Output Capacitance	C <sub>oss</sub>		---	720	---	
Reverse Transfer Capacitance	C <sub>rss</sub>		---	40	---	
<b>Switching Characteristics</b>						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =20V , V <sub>GS</sub> =10V , I <sub>D</sub> =55A	---	46	---	nC
Gate-Source Charge	Q <sub>gs</sub>		---	8	---	
Gate-Drain Charge	Q <sub>gd</sub>		---	7.5	---	
Turn-On Delay Time	T <sub>d(on)</sub>	V <sub>DD</sub> =20V , V <sub>GS</sub> =10V , R <sub>G</sub> =1.6Ω, I <sub>D</sub> =55A	---	10	---	ns
Rise Time	T <sub>r</sub>		---	5	---	
Turn-Off Delay Time	T <sub>d(off)</sub>		---	32	---	
Fall Time	T <sub>f</sub>		---	5.5	---	
<b>Diode Characteristics</b>						
Diode Forward Voltage <sup>2</sup>	V <sub>SD</sub>	V <sub>GS</sub> =0V , I <sub>S</sub> =1A , T <sub>J</sub> =25°C	---	---	1.2	V

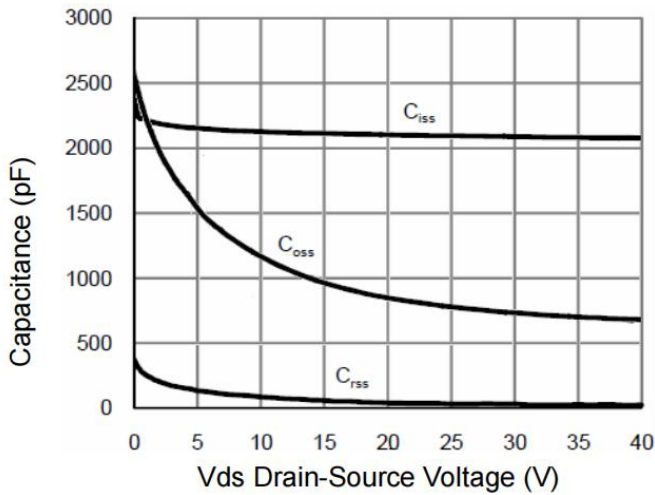
**Note :**

- The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
  - The data tested by pulsed , pulse width ≦ 300us , duty cycle ≦ 2%
- The EAS data shows Max. rating . The test condition is V<sub>DD</sub>=20V,V<sub>GS</sub>=10V,L=0.5mH,R<sub>G</sub>=25Ω

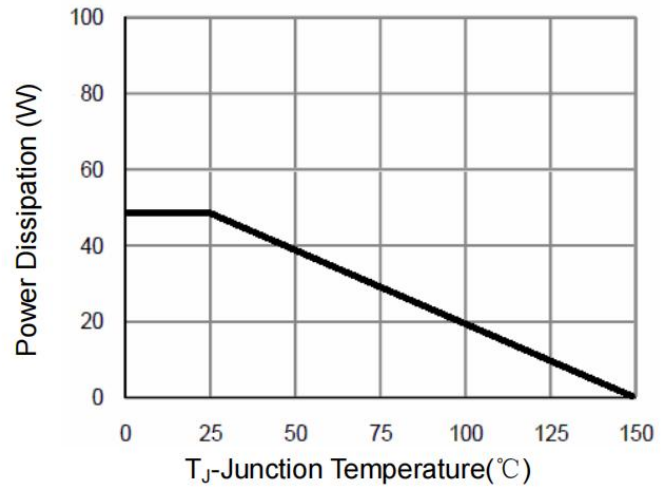


Typical Characteristics

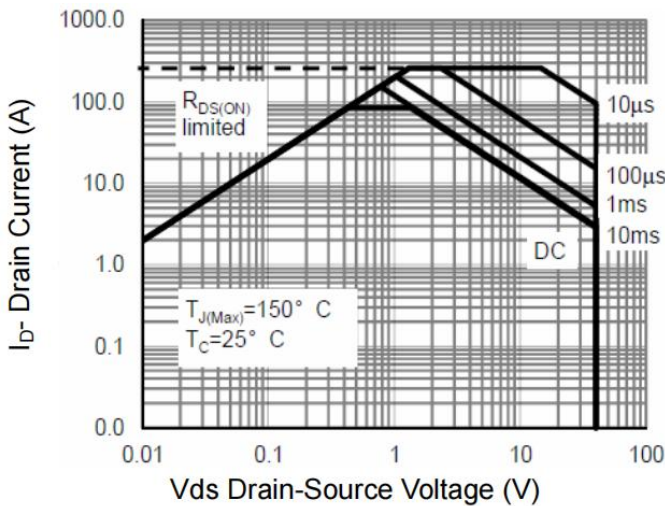




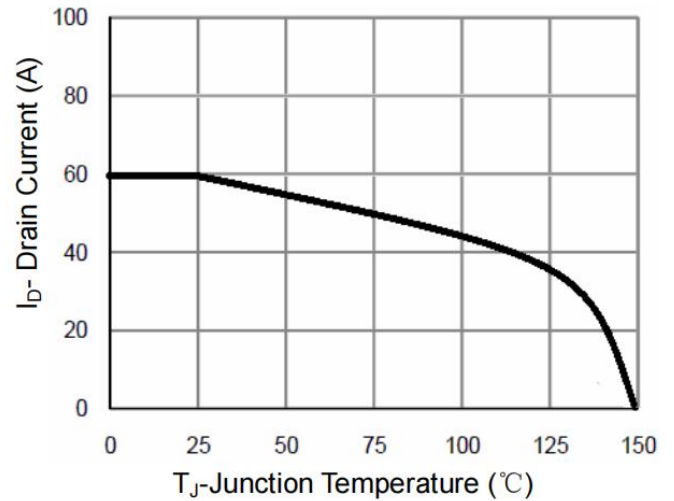
Capacitance vs Vds



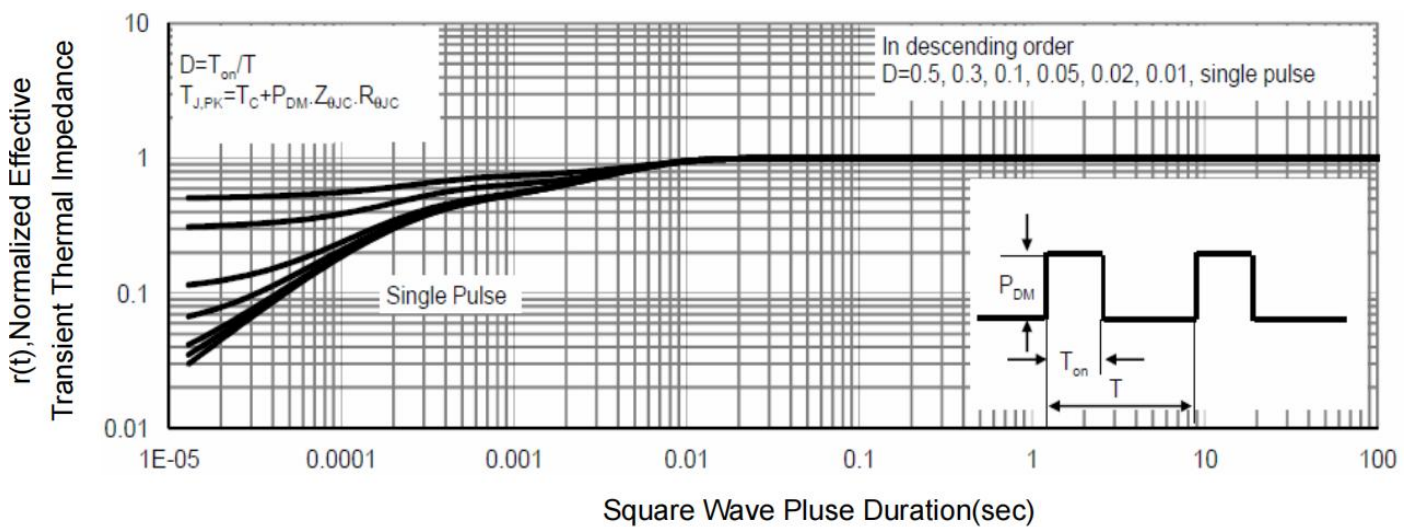
Power De-rating



Safe Operation Area



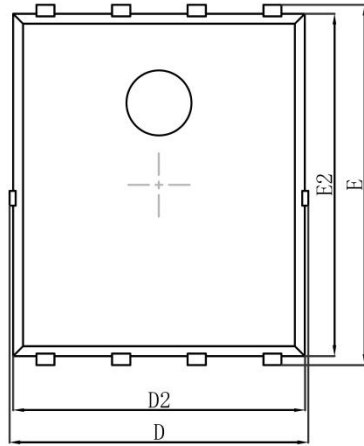
Current De-rating



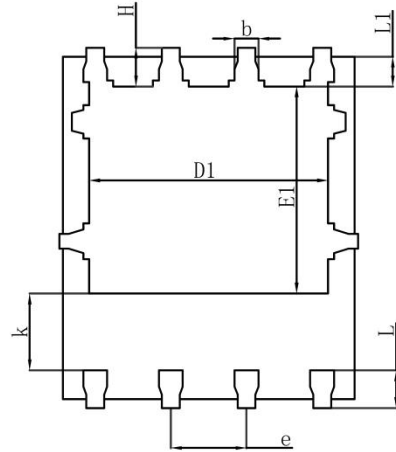
Normalized Maximum Transient Thermal Impedance



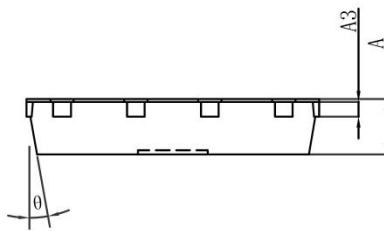
PDFN5X6-8L Package Information



Top View  
[顶视图]



Bottom View  
[背视图]



Side View  
[侧视图]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.000	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.944	5.096	0.195	0.201
E	5.974	6.126	0.235	0.241
D1	3.910	4.110	0.154	0.162
E1	3.375	3.575	0.133	0.141
D2	4.824	4.976	0.190	0.196
E2	5.674	5.826	0.223	0.229
k	1.190	1.390	0.047	0.055
b	0.350	0.450	0.014	0.018
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°

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